
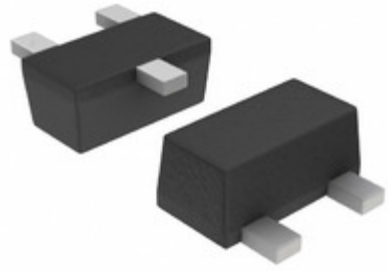





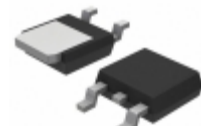
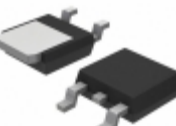

	<h2 style="color: red;">NSS20101JT1G</h2>
	<p>Hersteller-Teilenummer: NSS20101JT1G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: TRANS NPN 20V 1A SC-89</p> <hr/> <p>Datenblätter:  NSS20101JT1G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 24420 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NSS20101JT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS NPN 20V 1A SC-89
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	24420 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	300mW
Verpackung / Gehäuse	SC-89, SOT-490
Supplier Device-Gehäuse	SC-89-3
Transistor-Typ	NPN
Strom - Kollektor (Ic) (max)	1A
Spannung - Kollektor-Emitter-Durchbruch (max)	20V
VCE Sättigung (Max) @ Ib, Ic	220mV @ 100mA, 1A
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	200 @ 100mA, 2V
Frequenz - Übergang	350MHz
Verpackung	Tape & Reel (TR)

NSS20101JT1G ist neu im Original, Suche NSS20101JT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NSS20101JT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NSS20101JT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NSS20200W6T1G AMI Semiconductor / ON Semiconductor TRANS PNP 20V 2A SC-88</p>	 <p>NSS200-50 NAE IGBT Modules</p>	 <p>NSS1C201MZ4T1G AMI Semiconductor / ON Semiconductor TRANS NPN 100V 2A SOT223-4</p>	 <p>NSS20201MR6T1G AMI Semiconductor / ON Semiconductor TRANS NPN 20V 2A TSOP-6</p>
 <p>NSS20201LT1G AMI Semiconductor / ON Semiconductor TRANS NPN 20V 2A SOT-23</p>	 <p>NSS1C301ET4G AMI Semiconductor / ON Semiconductor TRANS NPN 100V 3A 3DPAK</p>	 <p>NSS1C300ET4G AMI Semiconductor / ON Semiconductor TRANS PNP 100V 3A 3DPAK</p>	 <p>NSS20101ST1G ON ON SOT523</p>

heiße Teile

Mehr

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NSS1C201LT1G	NSS1C201MZ4T1G	NSS1C201MZ4T3G	NSS200-50	NSS20200LT1G
D NSS20201LT1G	NSS20201MR6T1G	NSS20300MR6T1G	NSS20500UW3T2G	NSS30070MR6T1G
NSS30071MR6T1G	NSS30100LT1G	NSS30101LT1G	NSS3010LT1G	NSS30201MR6T1G
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NSS60601MZ4T3G	OP497GSZ	NSS12100M3T5G	SMAJ28A-E3/61	SN74ALVTH16827DLR

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